



P.E.S. College of Engineering, Mandya - 571 401

(An Autonomous Institution affiliated to VTU, Belagavi)

Third Semester, B.E. - Electrical and Electronics Engineering

Semester End Examination; March / April - 2022

Analog Electronic Circuits

Time: 3 hrs

Max. Marks: 100

Course Outcomes

The Students will be able to:

CO1: Analyze and design Diode and Transistor circuit such as Clippers, Clampers, Voltage Multipliers and Amplifiers.

CO2: Analyze and design two port hybrid equivalent model for BJT amplifier and Various BJT Oscillator Circuits.

CO3: Analyze the effect of negative feedback in transistor amplifier.

CO4: Analyze and design various Power amplifier circuits and study the effect of distortions on Power amplifier.

CO5: Analysis of J-FET and MOSFET Circuit.

Note: I) PART - A is compulsory. Two marks for each question.

II) PART - B: Answer any Two sub questions (from a, b, c) for Maximum of 18 marks from each unit.

Q. No.	Questions	Marks	BLs	COs	POs
I : PART - A		10			
I a.	Draw the circuit of series clipper to clip the input sinusoidal signal below V_R . Sketch the input and output waveforms.	2	L1	CO1	PO1
b.	Write the h-parameter equations for common base mode and hence draw its h-parameter model.	2	L2	CO2	PO2
c.	State any two merits of negative feedback amplifier.	2	L3	CO3	PO1
d.	State any two features of Class A and Class B power amplifiers.	2	L3	CO4	PO4
e.	Show that the amplification factor in JFET is given by $\mu = r_d \times g_m$.	2	L2	CO5	PO2
II : PART - B		90			
UNIT - I		18			

- 1 a. For the clipping circuit as in Fig. 1(a) draw the transfer characteristics draw input and output voltage waveforms. Assume $V_i = 50 \sin \omega t$.

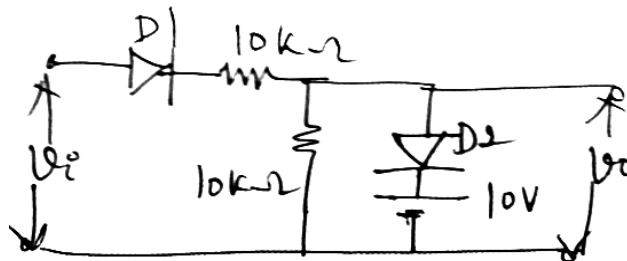


Fig. 1(a)

- b. For the voltage divider bias circuit $R_C = 1 \text{ k}\Omega$, $R_E = 470 \Omega$, $R_1 = 10 \text{ k}\Omega$, $R_2 = 5 \text{ k}\Omega$, $V_{CC} = 10 \text{ V}$, $\beta = 100$. Find the location of Q point (I_C , V_{CE}). Draw the circuit diagram.
- c. Explain the high frequency responses of an amplifier with circuit diagram and obtain gain and phase response with diagram.

UNIT - II

18

- 2 a. For the transistor amplifier in general form, derive expression for A_I , Z_i , A_V and Z_o . 9 L3 CO1 PO4
- b. A single stage common emitter amplifier has $R_S = 1 \text{ k}\Omega$, $R_I = 50 \text{ k}\Omega$, $R_2 = 2 \text{ k}\Omega$, $R_E = 500 \Omega$, $R_C = 1 \text{ k}\Omega$, $R_L = 1.2 \text{ k}\Omega$, $C_E = 47 \mu\text{F}$, $h_{ie} = 1.1 \text{ k}\Omega$, $h_{fe} = 50$, $h_{oe} = 25 \mu\text{A/V}$ and $h_{re} = 2.5 \times 10^{-4}$. Calculate A_I , Z_i , A_V and A_{VS} . Draw the circuit diagram. 9 L1 CO2 PO2
- c. Explain the working of RC phase shift oscillator. State expressions for f_0 and h_{fe} min of transistor. If $f_0 = 1 \text{ kHz}$, $C = 0.1 \mu\text{F}$, calculate the resistance R of the above oscillator circuit. 9 L1 CO2 PO2

UNIT - III

18

- 3 a. Explain the concept of feedback. Draw the required diagrams. 9 L2 CO3 PO3
- b. For the voltage series feedback amplifier, obtain expressions for R_{if} and R_{of} . 9 L2 CO3 PO3
- c. For the current series feedback amplifier $R_L = 2.2 \text{ k}\Omega$, $R_E = 1.2 \text{ k}\Omega$, $R_S = 1 \text{ k}\Omega$, calculate; β , D , G_m , A_{VF} , R_{if} , and R_{of}' . Draw the circuit diagram. 9 L1 CO3 PO1
Given $h_{fe} = 50$, $h_{ie} = 1.1 \text{ k}\Omega$.

UNIT - IV

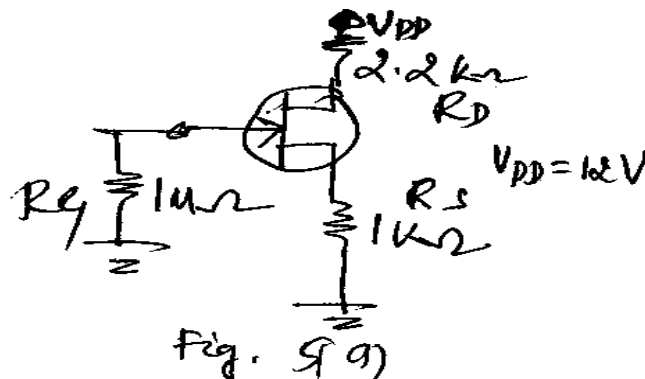
18

- 4 a. Explain class 'B' power amplifier circuit with related waveform and obtain conversion efficiency. 9 L1 CO2 PO2
- b. Explain harmonic distortion in power amplifiers. Derive an expression for II harmonic distortion. 9 L2 CO4 PO3
- c. A class-B push-pull amplifier is operated with $V_{CC} = 10 \text{ V}$ and $R_L = 5 \Omega$, determine the maximum output power, power ratings of transistors and dc input power. Draw the circuit diagram also. 9 L1 CO3 PO1

UNIT - V

18

- 5 a. In JFET, show that $g_m = g_{m0} \left(1 - \frac{V_{GS}}{V_P} \right)$. For the circuit of Fig. 5(a) determine V_{GSQ} , I_{DQ} , V_{DS} , V_S , V_D . Assume $I_{DSS} = 8 \text{ mA}$, $V_P = -4 \text{ V}$, $V_{DD} = 2 \text{ V}$.



9 L2 CO3 PO1

- b. Explain the construction and working of n-channel D-MOSFET. 9 L3 CO1 PO1
- c. Explain the construction and working of P-channel J-FET. 9 L1 CO2 PO2